DUSEU

Bipolar Transistor

-20 V, -5 A, Low V_{CF}(sat), PNP Single PCP

2SB1302

Features

- Adoption of FBET, MBIT Processes
- Large Current Capacity
- Ultrasmall Size Making it Easy to Provide High-Density Small-Sized Hybrid IC's
- Low Collector to Emitter Saturation Voltage
- Fast Switching Speed
- These Devices are Pb-Free and are RoHS Compliant

Applications

• DC-DC Converters, Motor Drivers, Relay Drivers, Lamp Drivers

SPECIFICATIONS ABSOLUTE MAXIMUM RATINGS at Ta = 25°C

| SPECIFICATIONS ABSOLUTE MAXIMUM RATING | S at Ta = 25∘C | | | DEDFONSE |
|---|-----------------------|-------------|------|---------------|
| Parameter | Symbol | Value | Unit | NR 21 |
| Collector to Base Voltage | V _{CBO} | -25 | N - | 100°C04 |
| Collector to Emitter Voltage | V _{CEO} | -20 | V | 1 Jr |
| Emitter to Base Voltage | V _{EBO} | -5 | V] | R |
| Collector Current | lc | -5 | А | ORDE |
| Collector Current (Pulse) | ICP | C-8 | X | Device |
| Collector Dissipation (Note 1) | SPC | 1.3 | Ŵ | |
| Junction Temperature | | 150 | °C | 2SB1302S-TD- |
| Storage Temperature | T _{STG} | -55 to +150 | °C | 2SB1302T-TD-I |

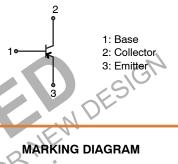
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface mounted on ceramic substrate (250 mm² x 0.8 mm).



SOT-89 / PCP-1 CASE 419AU

ELECTRICAL CONNECTION



ORDERING INFORMATION

| Device | Package | Shipping [†] | |
|---------------|------------------|-----------------------|--|
| 2SB1302S-TD-E | PCP (Pb-Free) | 1000 / Tape & Reel | |
| 2SB1302T-TD-E | PCP (Pb-Free) | 1000 / Tape & Reel | |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

2SB1302

ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}C$

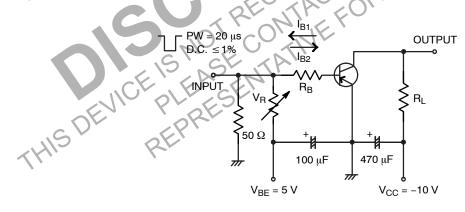
| | | | Ratings | | | |
|---|-----------------------|--|---------|------|------|------|
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
| Collector Cutoff Current | I _{CBO} | $V_{CB} = -20 \text{ V}, I_E = 0 \text{ A}$ | | | -500 | nA |
| Emitter Cutoff Current | I _{EBO} | $V_{EB} = -4V, I_{C} = 0 A$ | | | -500 | nA |
| DC Current Gain | h _{FE} 1 | $V_{CE} = -2 \text{ V}, \text{ I}_{C} = -500 \text{ mA}$ | 140* | | 400* | |
| | h _{FE} 2 | $V_{CE} = -2 V, I_{C} = -4 A$ | 60 | | | |
| Gain-Bandwidth Product | f _T | $V_{CE} = -5 \text{ V}, \text{ I}_{C} = -200 \text{ mA}$ | | 320 | | MHz |
| Output Capacitance | Cob | V _{CB} = -10 V, f = 1 MHz | | 60 | | pF |
| Collector to Emitter Saturation Voltage | V _{CE} (sat) | I _C = -3 A, I _B = -60 mA | | -250 | -500 | mV |
| Base to Emitter Saturation Voltage | V _{BE} (sat) | I _C = -3 A, I _B = -60 mA | | -1.0 | -1.3 | V |
| Collector to Base Breakdown Voltage | V _{(BR)CBO} | $I_{C} = -10 \ \mu A, \ I_{E} = 0 \ A$ | -25 | | | V |
| Collector to Emitter Breakdown Voltage | V _{(BR)CEO} | $I_{C} = -1 \text{ mA}, R_{BE} = \infty$ | -20 | | 2 | V |
| Emitter to Base Breakdown Voltage | V _{(BR)EBO} | I _E = -10 μA, I _C = 0 A | -5 | | G | V |
| Turn–On Time | t _{on} | See specified Test Circuit | | 40 | ES. | ns |
| Storage Time | t _{stg} | | | 200 |) | ns |
| Fall Time | t _f | | | 10 | | ns |

NUT ORMATION Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

*2SB1302 is classified by 500 mA $h_{\mbox{\scriptsize FE}}$ as follows :

| Rank | S | Т | | |
|-----------------|------------|------------|--|--|
| h _{FE} | 140 to 280 | 200 to 400 | | |

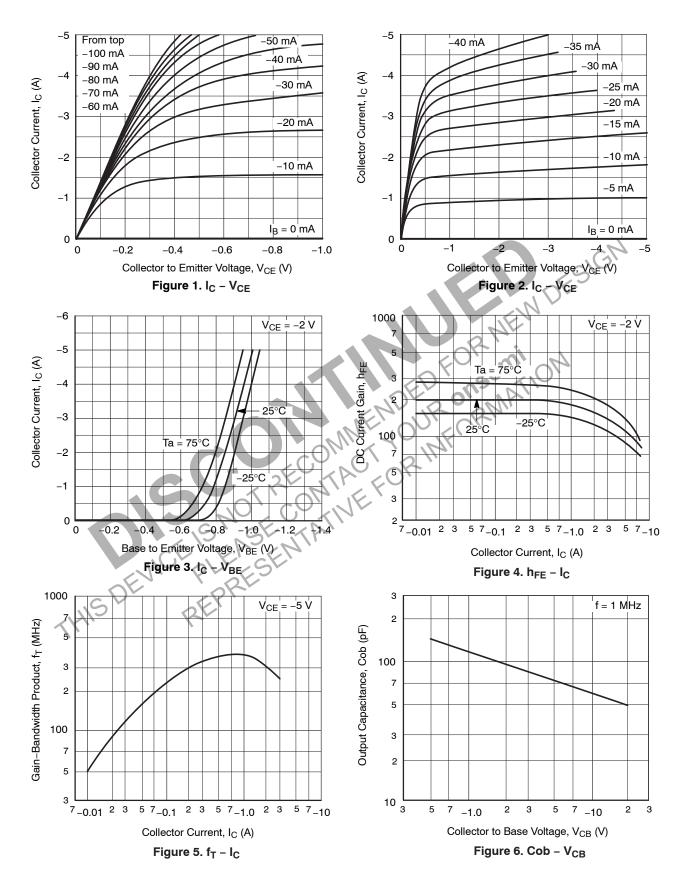
Switching Time Test Circuit



 $I_{\rm C} = 10 \ I_{\rm B1} = -10 \ I_{\rm B2} = -2 \ {\rm A}$

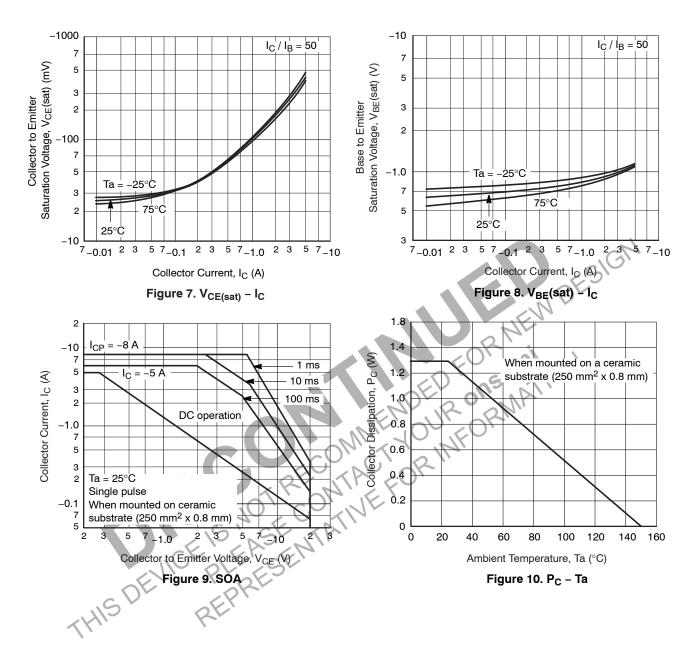
2SB1302

TYPICAL CHARACTERISTICS



2SB1302

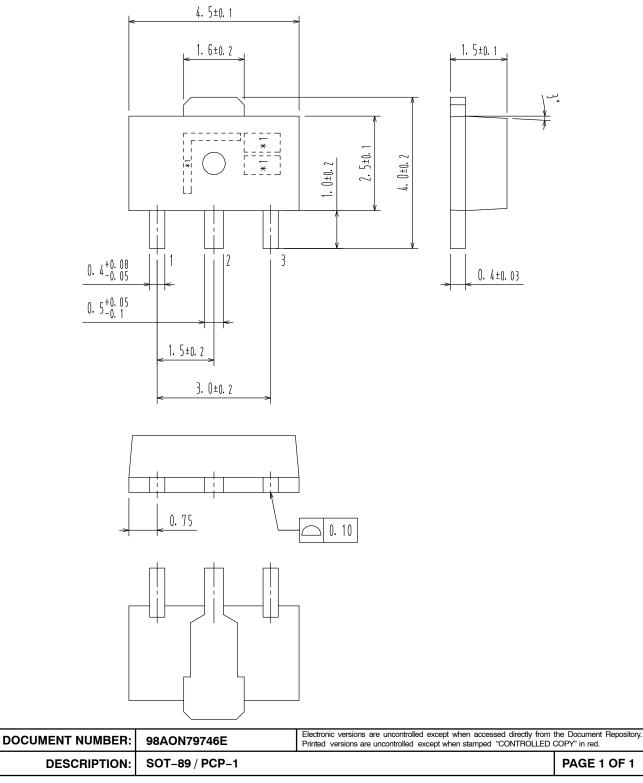
TYPICAL CHARACTERISTICS (continued)





SOT-89 / PCP-1 CASE 419AU ISSUE O

DATE 30 APR 2012



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